

2N2905A

Small Signal Switching Transistor

PNP Silicon

Features

- MIL-PRF-19500/290 Qualified
- Available as JAN, JANTX, and JANTXV

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V_{CEO}	-60	Vdc
Collector - Base Voltage	V_{CBO}	-60	Vdc
Emitter - Base Voltage	V_{EBO}	-5.0	Vdc
Collector Current - Continuous	I_C	-600	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$	P_T	800	mW
Total Device Dissipation @ $T_C = 25^\circ\text{C}$	P_T	3.0	W
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200	$^\circ\text{C}$

THERMAL CHARACTERISTICS

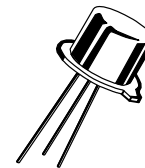
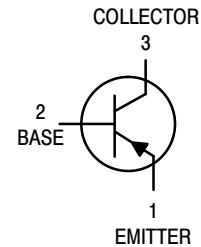
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	195	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	50	$^\circ\text{C}/\text{W}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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TO-39
CASE 205AB
STYLE 1

ORDERING INFORMATION

Device	Package	Shipping
JAN2N2905A	TO-39	Bulk
JANTX2N2905A		
JANTXV2N2905A		

2N2905A

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Breakdown Voltage (Note 1) (I _C = -10 mA _{dc})	V _{(BR)CEO}	-60	-	V _{dc}
Collector–Emitter Cutoff Current (V _{CE} = -60 V _{dc})	I _{CES}	-	-1.0	μA _{dc}
Collector–Base Cutoff Current (V _{CB} = -50 V _{dc}) (V _{CB} = -60 V _{dc})	I _{CBO}	- -	-10 -10	nA _{dc} μA _{dc}
Emitter–Base Cutoff Current (V _{EB} = -5.0 V _{dc}) (V _{EB} = -3.5 V _{dc})	I _{EBO}	- -	-10 -50	μA _{dc} nA _{dc}
ON CHARACTERISTICS (Note 1)				
DC Current Gain (I _C = -0.1 mA _{dc} , V _{CE} = -10 V _{dc}) (I _C = -1.0 mA _{dc} , V _{CE} = -10 V _{dc}) (I _C = -10 mA _{dc} , V _{CE} = -10 V _{dc}) (I _C = -150 mA _{dc} , V _{CE} = -10 V _{dc}) (I _C = -500 mA _{dc} , V _{CE} = -10 V _{dc})	h _{FE}	75 100 100 100 50	- 450 - 300 -	-
Collector–Emitter Saturation Voltage (I _C = -150 mA _{dc} , I _B = -15 mA _{dc}) (I _C = -500 mA _{dc} , I _B = -50 mA _{dc})	V _{CE(sat)}	- -	-0.4 -1.6	V _{dc}
Base–Emitter Saturation Voltage (I _C = -150 mA _{dc} , I _B = -15 mA _{dc}) (I _C = -500 mA _{dc} , I _B = -50 mA _{dc})	V _{BE(sat)}	- -	-1.3 -2.6	V _{dc}
SMALL–SIGNAL CHARACTERISTICS				
Magnitude of Small Signal Current Gain (I _C = -50 mA _{dc} , V _{CE} = -20 V _{dc} , f = 100 MHz)	h _{fe}	2.0	-	-
Small Signal Current Gain (I _C = -1.0 mA _{dc} , V _{CE} = -10 V _{dc} , f = 1 kHz)	h _{fe}	100	-	-
Output Capacitance (V _{CB} = -10 V _{dc} , I _E = 0, 100 kHz ≤ f ≤ 1.0 MHz)	C _{obo}	-	8.0	pF
Input Capacitance (V _{EB} = -2.0 V _{dc} , I _C = 0, 100 kHz ≤ f ≤ 1.0 MHz)	C _{ibo}	-	30	pF
SWITCHING CHARACTERISTICS				
Turn–On Time (Reference Figure in MIL–PRF–19500/290)	t _{on}	-	45	ns
Turn–Off Time (Reference Figure in MIL–PRF–19500/290)	t _{off}	-	300	ns

1. Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

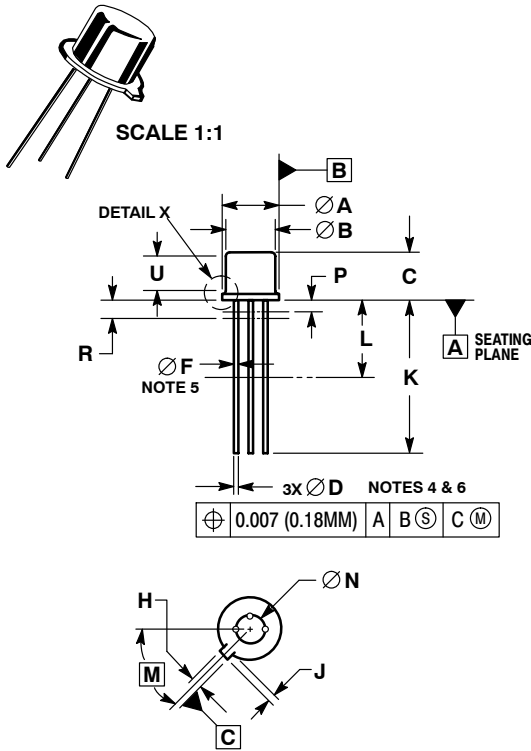
MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

ON Semiconductor®



TO-39 3-Lead
CASE 205AB
ISSUE A

DATE 25 JUN 2012



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSION J MEASURED FROM DIAMETER A TO EDGE.
4. LEAD TRUE POSITION TO BE DETERMINED AT THE GAUGE PLANE DEFINED BY DIMENSION R.
5. DIMENSION F APPLIES BETWEEN DIMENSION P AND L.
6. DIMENSION D APPLIES BETWEEN DIMENSION L AND K.
7. BODY CONTOUR OPTIONAL WITHIN ZONE DEFINED BY DIMENSIONS A, B, AND T.
8. DIMENSION B SHALL NOT VARY MORE THAN 0.010 IN ZONE P.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.89	9.40	0.350	0.370
B	8.00	8.51	0.315	0.335
C	6.10	6.60	0.240	0.260
D	0.41	0.48	0.016	0.019
E	0.23	3.18	0.009	0.125
F	0.41	0.48	0.016	0.019
H	0.71	0.86	0.028	0.034
J	0.73	1.02	0.029	0.040
K	12.70	14.73	0.500	0.580
L	6.35	---	0.250	---
M	45° BSC		45° BSC	
N	5.08 BSC		0.200 BSC	
P	---	1.27	---	0.050
R	1.37 BSC		0.054 BSC	
T	---	0.76	---	0.030
U	2.54	---	0.100	---

STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

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